ALCDA12C-1 through ALCDA24C-1 Low Capacitance TVS Diode Array

Description

The ALCDAXXC-1 is a low capacitance TVS diode array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting sensitive semiconductor components from damage. The ALCDAXXC-1 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into a lead-free SOT-143 package. It is designed to protect components which are connected to high speed interfaces and transmission lines from voltage surges.

Features

- 300W peak pulse power (8/20µs)
- Ultra low leakage: nA level
- Operating voltage: 12V, 15V, 24V
- Low capacitance for high-speed data line
- Low clamping voltage
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 Air discharge: ±30kV
- Contact discharge: ±30kV
- RoHS Compliant

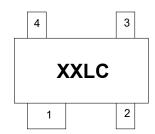
Mechanical Characteristics

- Package: SOT-143Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

- ADSL Interfaces
- Wireless Systems
- Portable Instrumentation
- LAN/WAN equipment
- High-Speed Data Lines
- Multi-Protocol Serial Transceivers
- RS-232, RS-422, V.90 Interfacess

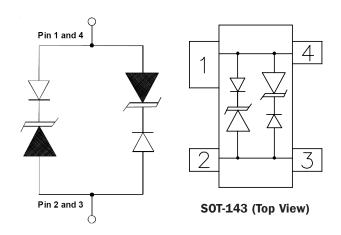
Marking Information



Part Number	Marking
ALCDA12C-1	12LC
ALCDA15C-1	15LC
ALCDA24C-1	24LC

Ordering Information

Dimensions and Pin Configuration



Part Number	Reel Size	
ALCDA12C-1	3000/Tape & Reel	7 inch
ALCDA15C-1	3000/Tape & Reel	7 inch
ALCDA24C-1	3000/Tape & Reel	7 inch

Circuit Diagram

Pin Schematic



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	300	W
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±30 ±30	kV
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

ALCDA12C-1							
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition	
Reverse Working Voltage	VRWM			12	V		
Breakdown Voltage	VBR	13.3			V	IT = 1mA	
Reverse Leakage Current	I _R			0.5	μΑ	VRWM = 12V	
Clamping Voltage	Vc			18	V	IPP = 5A (8 x 20μs pulse)	
Clamping Voltage	Vc			25	V	IPP = 12A (8 x 20µs pulse)	
Peak Pulse Current	IPP			12	Α	t _P = 8/20µs	
Junction Capacitance	CJ		8	15	pF	VR = 0V, f = 1MHz, between I/O pins and GND	



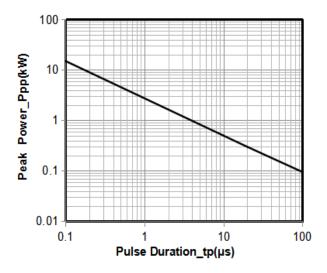
ALCDA12C-1 through ALCDA24C-1

ALCDA15C-1								
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition		
Reverse Working Voltage	VRWM			15	V			
Breakdown Voltage	VBR	16.7			V	IT = 1mA		
Reverse Leakage Current	I _R			0.5	μA	VRWM = 15V		
Clamping Voltage	Vc			24	V	IPP = 1A (8 x 20µs pulse)		
Clamping Voltage	Vc			30	V	IPP = 10A (8 x 20µs pulse)		
Peak Pulse Current	IPP			10	Α	t _p = 8/20µs		
Junction Capacitance	Сл		8	15	pF	VR = 0V, f = 1MHz, between I/O pins and GND		

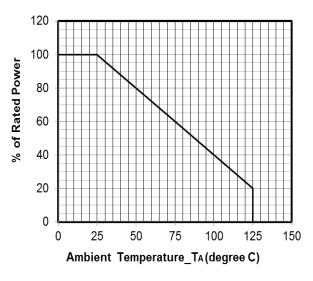
ALCDA24C-1							
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition	
Reverse Working Voltage	VRWM			24	V		
Breakdown Voltage	VBR	27			V	IT = 1mA	
Reverse Leakage Current	I _R			0.2	μA	VRWM = 24V	
Clamping Voltage	Vc			38	V	IPP = 1A (8 x 20µs pulse)	
Clamping Voltage	Vc			60	V	IPP = 5A (8 x 20µs pulse)	
Peak Pulse Current	IPP			5	Α	t _p = 8/20µs	
Junction Capacitance	CJ		8	15	pF	VR = 0V, f = 1MHz, between I/O pins and GND	



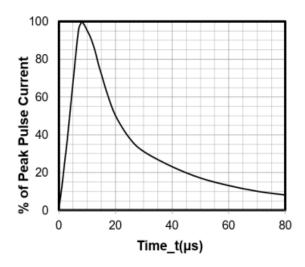
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



Peak Pulse Power vs. Pulse Time



Power Derating Curve

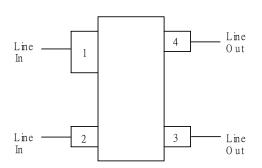


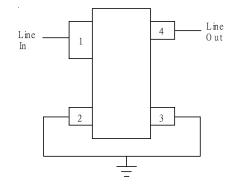
8 X 20µs Pulse Waveform



Device Connection for Protection of High-Speed Data Line

The ALCDAxxC-1 is designed to protect high-speed data lines from transient over-voltages which result from lightning and ESD. The device is designed to protect one line in common mode (Line-to-Ground) or one line pair in metallic (Line-to-Line) mode. For metallic modeprotection, the input of line 1 is connected at pin 1 and the output is connected at pin 4. Likewise, the input of line 2 is connected at pin 2 and the output is connected at pin 3. For common mode protection ground either pins 1 and 4 or pins 2 and 3. The ground connection should be made directly to the ground plane for best results.

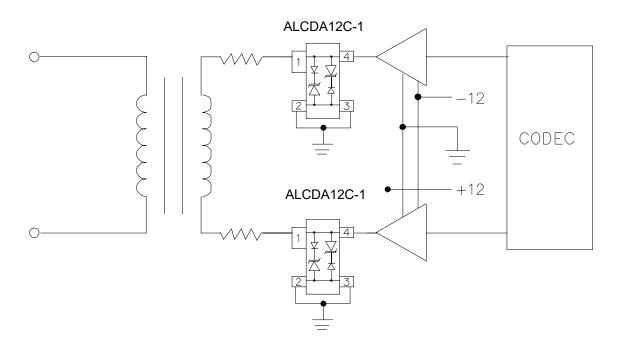




Connection for Differential Protection

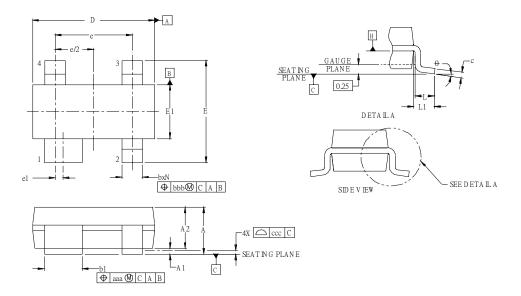
Connection for Common Mode

ALCDA12C-1 on ADSL Application



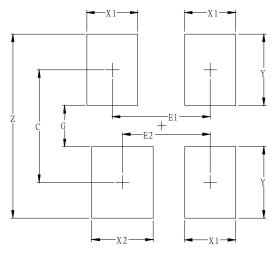


SOT-143 Package Outline Drawing



	D IM EN SIONS							
D 114	I	NCHE	ES	M ILLIM ETERS				
D IM	M IN	NOM	MAX	M IN	NOM	MAX		
A	£031	-	.048	0.80	-	1.22		
A 1	.000	-	.006	0.013	-	0.15		
A2	.029	.035	.042	0.75	0.90	1.07		
b	Ω11	-	.020	0.30	-	0.51		
b1	.029	-	.037	0.76	-	0.94		
С	.003	-	.008	0.08	-	0.20		
D	.110	.114	.120	2.80	2.90	3.04		
E	.082	.093	.104	2.10	2.37	2.64		
E1	Ω47	.051	.055	1.20	1.30	1.40		
e		.075		1.92 BSC				
e1		8 00.		0.20 BSC				
L	.015	Ω20	.024	0.40	0.50	0.60		
L1		(D21)		(0.54)				
N		4			- 4			
+	0°	-	8°	0° - 8°				
aaa	.006			0.15				
bb b		.008		0.20				
ccc		00.4		0.10				

Suggested Land Pattern



CVM	DIMENSIONS				
SYM	MILLIMETERS	INCHES			
С	2.20	0.087			
E1	1.92	0.076			
E2	1.72	0.068			
G	0.80	0.031			
X1	1.00	0.039			
X2	1.20	0.047			
Υ	1.40	0.055			
Z	3.60	0.141			

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